

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω)(Typ.)	I _D (A) ^{a, e}			
-30	7.5 at V _{GS} = -10 V	-60			
-30	10.8 at V _{GS} = -4.5 V	-48			

FEATURES

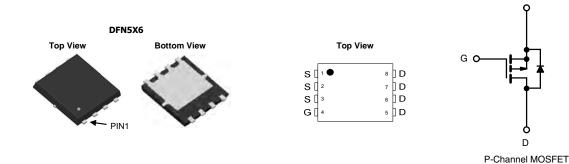
- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

APPLICATIONS

- Notebook
 - Load Switch







PARAMETER		SYMBOL	Limit	UNIT	
Drain-Source Voltage		V_{DS}	- 30	V	
Gate-Source Voltage		V_{GS}	± 20	7	
Continuo Dunia Comment /T 150 °C) 3	T _A = 25 °C	1	- 60		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	- 48		
Pulsed Drain Current		I _{DM}	- 240	Α	
Continuous Source Current (Diode Conduction) ^a		Is	- 60		
Avalanche Current	L = 0.1 mH	I _{AS}	- 55	1	
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	73	mJ	
Maximum Power Dissipation ^a	T _A = 25 °C	D	59	W	
Maximum Fower Dissipation -	T _A = 70 °C	P _D	37.7		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C	
Soldering Recommendations (Peak Temperature) b, c			260	1	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum Junction-to-Ambient b,d	t ≤ 10 s	- R _{thJA}	20	25		
waximum Junction-to-Ambient =,	Steady State		25	35	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.0	1.5		

- a. Based on T_C = 25 °C. b. Surface mounted on 1" x 1" FR4 board.

- d. Calculated based on maximum junction temperature.
 e. Single pulse width limited by junction temperature TJ(MAX)=150°C.

Rev. 1. 0 1



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static				•			
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	J. 250A		15		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = 250 \mu A$		-6.5			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1	-	-3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
Zoro Cata Valtaga Drain Current		V _{DS} = -30 V, V _{GS} = 0 V	-	-	-1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -24 V, V _{GS} = 0 V, T _J = 70 °C	-	-	-10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	-60	-	-	Α	
Drain Source On State Pecietanee 8	D	V _{GS} = -10 V, I _D = -15 A	-	7.5	9.9	mΩ	
Drain-Source On-State Resistance a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -10 \text{ A}$	-	10.8	13		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -15 \text{ V}, I_D = -15 \text{ A}$	-	65	-	S	
Dynamic ^b							
Input Capacitance	C _{iss}		-	3620	-	pF	
Output Capacitance	Coss	$V_{GS} = 0 \text{ V}, V_{DS} = 15 \text{ V}, f = 1 \text{ MHz}$	-	830	-		
Reverse Transfer Capacitance	C_{rss}		-	180	-		
Total Gate Charge	Q_g		-	123	-	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -15 \text{ A}$	-	20	-		
Gate-Drain Charge	Q_{gd}		-	34	-		
Gate Resistance	R_g		-	1.5	-	Ω	
Turn-On Delay Time	t _{d(on)}		-	20	-		
Rise Time	t _r	V_{DD} = -15 V, R_L = 30 Ω	-	23	-	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ -15 A, $V_{GEN}=$ -10 V, $R_g=6~\Omega$	-	55	-		
Fall Time	t _f		-	12	-		
Drain-Source Body Diode Characteris	tics						
Continuous Source-Drain Diode Current	I _S	$T_C = 25 ^{\circ}C$			60	A	
Pulse Diode Forward Current ^a	Ism				240		
Body Diode Voltage	V _{SD}	I _S = - 5 A		- 0.7	- 1	V	
Body Diode Reverse Recovery Time	t _{rr}			55		ns	
Body Diode Reverse Recovery Charge	Q _{rr}	L = 5 A dl/dt = 100 A/up T = 25 °C		68		nC	
Reverse Recovery Fall Time	t _a	$I_F = 5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 \text{ °C}$		25			
Reverse Recovery Rise Time	t _b			19		ns	

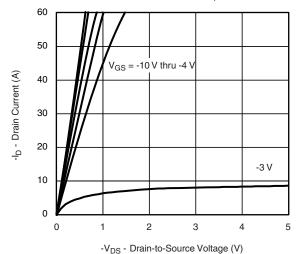
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

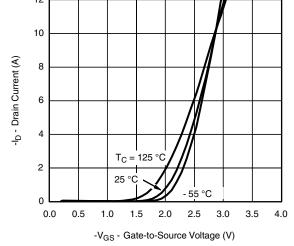
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



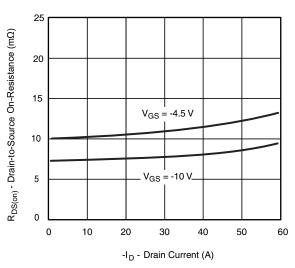
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



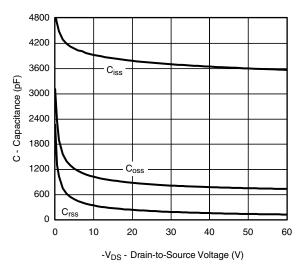
Output Characteristics



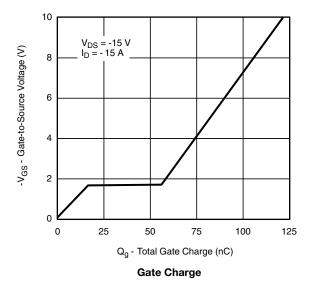
Transfer Characteristics

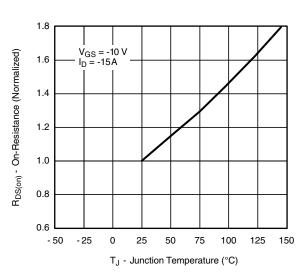


On-Resistance vs. Drain Current





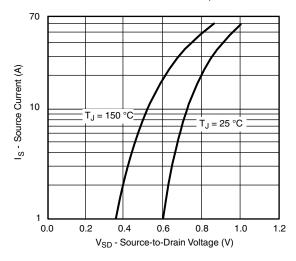




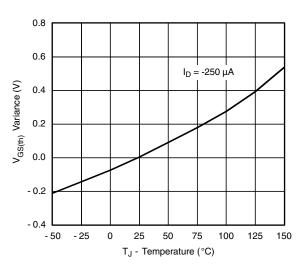
On-Resistance vs. Junction Temperature



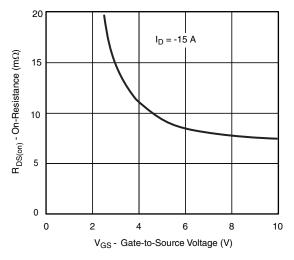
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



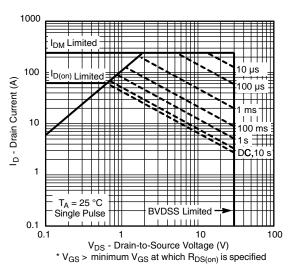
Source-Drain Diode Forward Voltage



Threshold Voltage



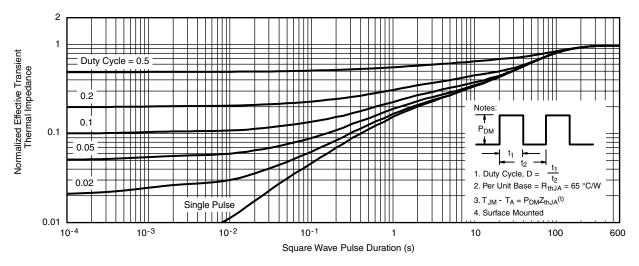
On-Resistance vs. Gate-to-Source Voltage



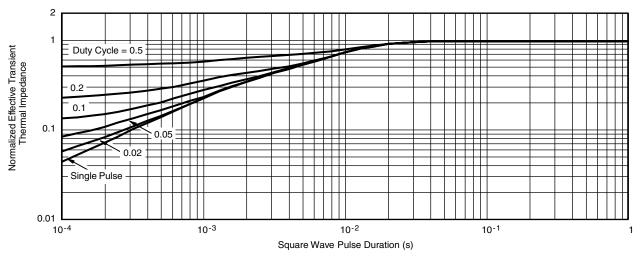
Safe Operating Area



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



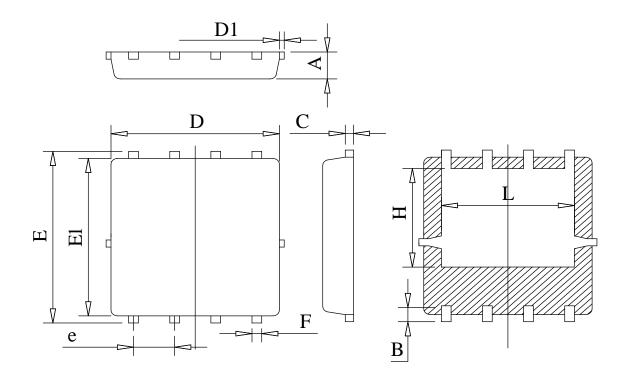
Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case



DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Unit: mm

Symbol	Min	Тур	Max
A	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25

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